## NSN 5961-01-246-2861

No Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-246-2861 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.785 inches **Terminal Length:** 0.135 inches **Overall Height:** 0.188 inches **Overall Width:** 0.263 inches **Component Name And Quantity:** 5 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 12.0 collector to base voltage/static/emitter open all transistor and 8.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**